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April 1st, 2010
Renesas Electronics Corporation

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R1RW0408D Series

4M High Speed SRAM (512-kword \times 8-bit)

REJ03C0111-0200

Rev. 2.00

Dec.1.2008

Description

The R1RW0408D is a 4-Mbit high speed static RAM organized 512-kword \times 8-bit. It has realized high speed access time by employing CMOS process (6-transistor memory cell) and high speed circuit designing technology. It is most appropriate for the application which requires high speed, high density memory and wide bit width configuration, such as cache and buffer memory in system. The R1RW0408D is packaged in 400-mil 36-pin SOJ for high density surface mounting.

Features

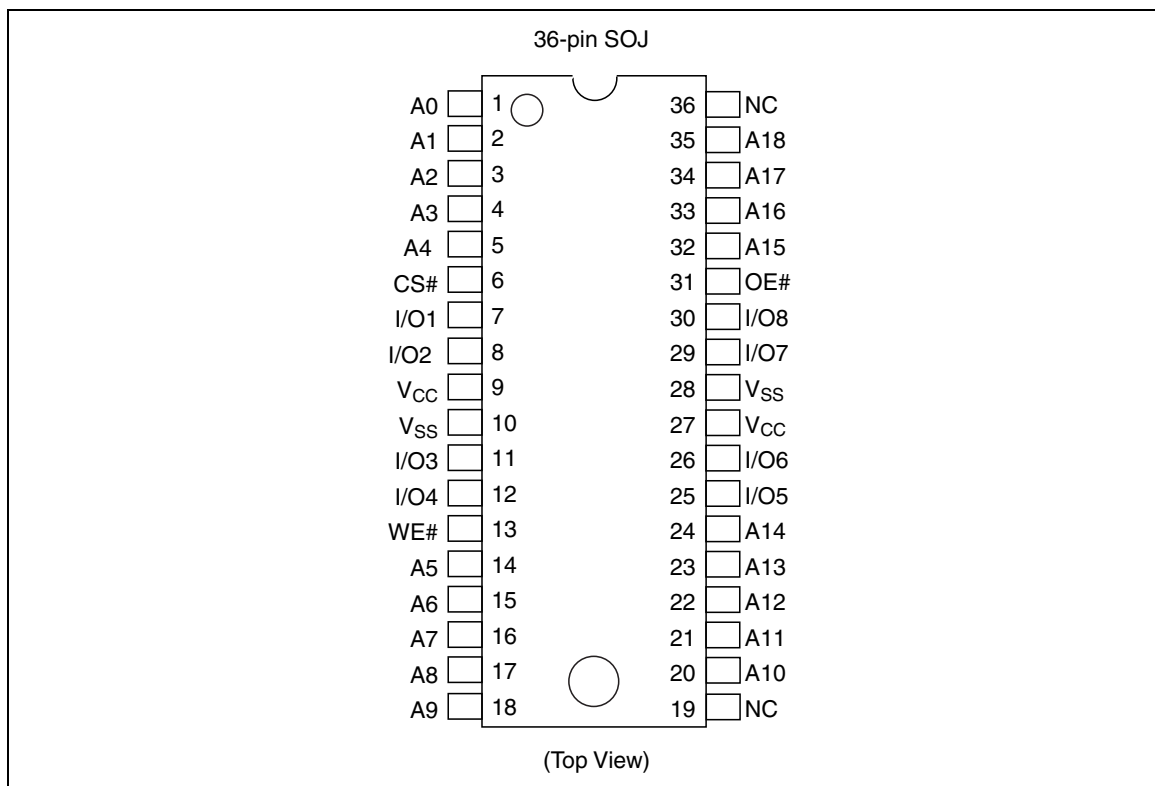
- Single supply: 3.3 V \pm 0.3 V
- Access time: 10 ns /12 ns (max)
- Completely static memory
 - No clock or timing strobe required
- Equal access and cycle times
- Directly TTL compatible
 - All inputs and outputs
- Operating current: 115mA/ 100mA (max)
- TTL standby current: 40 mA (max)
- CMOS standby current: 5 mA (max)
 - : 0.8 mA (max) (L-version)
- Data retention current: 0.4 mA (max) (L-version)
- Data retention voltage: 2 V (min) (L-version)
- Center V_{CC} and V_{SS} type pin out

R1RW0408D Series

Ordering Information

| Type No. | Access time | Package |
|-----------------|-------------|------------------------------------|
| R1RW0408DGE-0PR | 10 ns | 400-mil 36-pin plastic SOJ (36P0K) |
| R1RW0408DGE-2PR | 12 ns | |
| R1RW0408DGE-2LR | 12 ns | |

Pin Arrangement



Pin Description

| Pin name | Function |
|-----------------|-------------------|
| A0 to A18 | Address input |
| I/O1 to I/O8 | Data input/output |
| CS# | Chip select |
| OE# | Output enable |
| WE# | Write enable |
| V _{CC} | Power supply |
| V _{SS} | Ground |
| NC | No connection |

R1RW0408D Series

Operation Table

| CS# | OE# | WE# | Mode | V _{CC} current | I/O | Ref. cycle |
|-----|-----|-----|----------------|------------------------------------|------------------|-----------------------|
| H | × | × | Standby | I _{SB} , I _{SB1} | High-Z | — |
| L | H | H | Output disable | I _{CC} | High-Z | — |
| L | L | H | Read | I _{CC} | D _{OUT} | Read cycle (1) to (3) |
| L | H | L | Write | I _{CC} | D _{IN} | Write cycle (1) |
| L | L | L | Write | I _{CC} | D _{IN} | Write cycle (2) |

Note: H: V_{IH}, L: V_{IL}, ×: V_{IH} or V_{IL}

Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|-------------------|---|------|
| Supply voltage relative to V _{SS} | V _{CC} | −0.5 to +4.6 | V |
| Voltage on any pin relative to V _{SS} | V _T | −0.5* ¹ to V _{CC} + 0.5* ² | V |
| Power dissipation | P _T | 1.0 | W |
| Operating temperature | T _{opr} | 0 to +70 | °C |
| Storage temperature | T _{stg} | −55 to +125 | °C |
| Storage temperature under bias | T _{bias} | −10 to +85 | °C |

Notes: 1. V_T (min) = −2.0 V for pulse width (under shoot) ≤ 6 ns.

2. V_T (max) = V_{CC} + 2.0 V for pulse width (over shoot) ≤ 6 ns.

Recommended DC Operating Conditions

(T_a = 0 to +70°C)

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|--------------------------------|--------------------|-----|-------------------------------------|------|
| Supply voltage | V _{CC} * ³ | 3.0 | 3.3 | 3.6 | V |
| | V _{SS} * ⁴ | 0 | 0 | 0 | V |
| Input voltage | V _{IH} | 2.0 | — | V _{CC} + 0.5* ² | V |
| | V _{IL} | −0.5* ¹ | — | 0.8 | V |

Notes: 1. V_{IL} (min) = −2.0 V for pulse width (under shoot) ≤ 6 ns.

2. V_{IH} (max) = V_{CC} + 2.0 V for pulse width (over shoot) ≤ 6 ns.

3. The supply voltage with all V_{CC} pins must be on the same level.

4. The supply voltage with all V_{SS} pins must be on the same level.

R1RW0408D Series

DC Characteristics

(Ta = 0 to +70°C, V_{CC} = 3.3 V ± 0.3 V, V_{SS} = 0 V)

| Parameter | Symbol | Min | Max | Unit | Test conditions |
|--------------------------------|------------------|-----------------|-------|------|--|
| Input leakage current | I _{LI} | — | 2 | μA | V _{IN} = V _{SS} to V _{CC} |
| Output leakage current | I _{LO} | — | 2 | μA | V _{IN} = V _{SS} to V _{CC} |
| Operation power supply current | 10ns cycle | I _{CC} | — | 115 | Min cycle CS# = V _{IL} , I _{OUT} = 0 mA Other inputs = V _{IH} /V _{IL} |
| | 12ns cycle | I _{CC} | — | 100 | |
| Standby power supply current | I _{SB} | — | 40 | mA | Min cycle CS# = V _{IH} , Other inputs = V _{IH} /V _{IL} |
| | I _{SB1} | — | 5 | mA | f = 0 MHz V _{CC} ≥ CS# ≥ V _{CC} - 0.2 V, (1) 0 V ≤ V _{IN} ≤ 0.2 V or (2) V _{CC} ≥ V _{IN} ≥ V _{CC} - 0.2 V |
| | —*1 | — | 0.8*1 | mA | |
| Output voltage | V _{OL} | — | 0.4 | V | I _{OL} = 8 mA |
| | V _{OH} | 2.4 | — | V | I _{OH} = -4 mA |

Note: 1. This characteristics is guaranteed only for L-version.

Capacitance

(Ta = +25°C, f = 1.0 MHz)

| Parameter | Symbol | Min | Max | Unit | Test conditions |
|----------------------------|------------------|-----|-----|------|------------------------|
| Input capacitance*1 | C _{IN} | — | 6 | pF | V _{IN} = 0 V |
| Input/output capacitance*1 | C _{I/O} | — | 8 | pF | V _{I/O} = 0 V |

Note: 1. This parameter is sampled and not 100% tested.

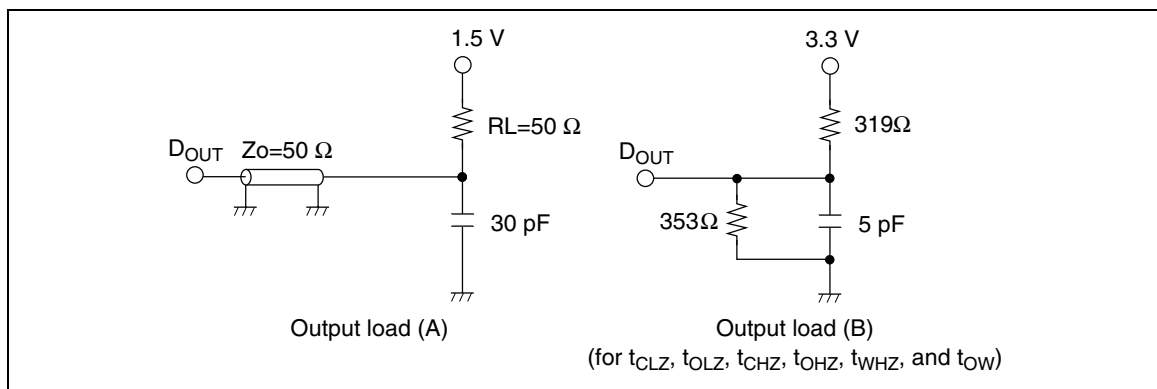
R1RW0408D Series

AC Characteristics

($T_a = 0$ to $+70^\circ\text{C}$, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$, unless otherwise noted.)

Test Conditions

- Input pulse levels: 3.0 V/0.0 V
- Input rise and fall time: 3 ns
- Input and output timing reference levels: 1.5 V
- Output load: See figures (Including scope and jig)



Read Cycle

| | | R1RW0408D | | | | | |
|------------------------------------|------------------|--------------|-----|--------------|-----|------|-------|
| | | 10ns Version | | 12ns Version | | | |
| Parameter | Symbol | Min | Max | Min | Max | Unit | Notes |
| Read cycle time | t _{RC} | 10 | — | 12 | — | ns | |
| Address access time | t _{AA} | — | 10 | — | 12 | ns | |
| Chip select access time | t _{ACS} | — | 10 | — | 12 | ns | |
| Output enable to output valid | t _{OE} | — | 5 | — | 6 | ns | |
| Output hold from address change | t _{OH} | 3 | — | 3 | — | ns | |
| Chip select to output in low-Z | t _{CLZ} | 3 | — | 3 | — | ns | 1 |
| Output enable to output in low-Z | t _{OLZ} | 0 | — | 0 | — | ns | 1 |
| Chip deselect to output in high-Z | t _{CHZ} | — | 5 | — | 6 | ns | 1 |
| Output disable to output in high-Z | t _{OHZ} | — | 5 | — | 6 | ns | 1 |

R1RW0408D Series

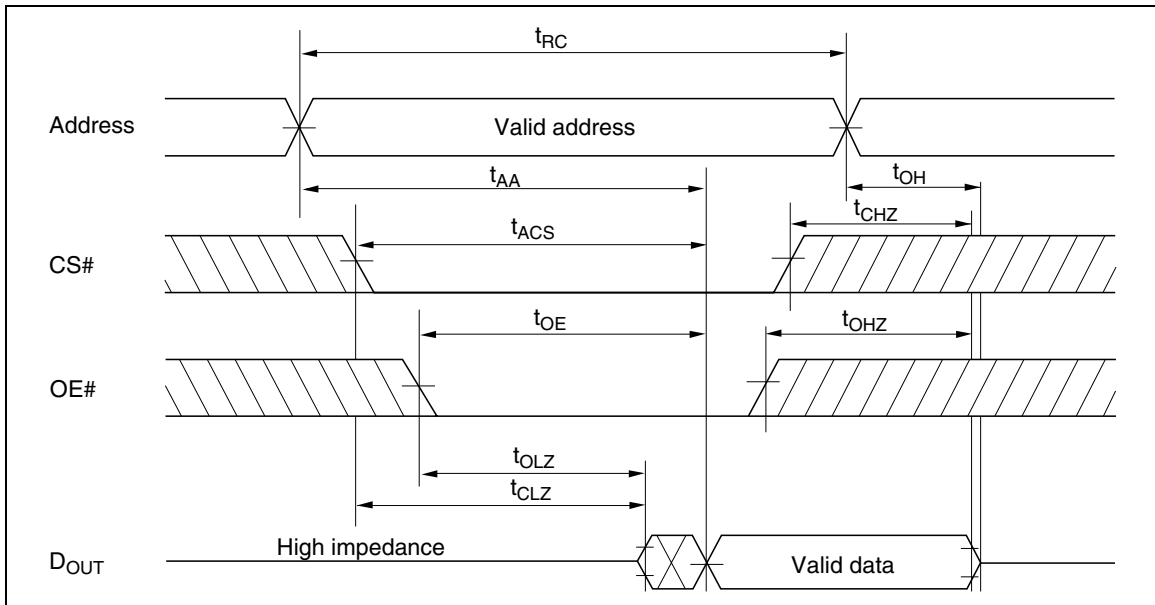
Write Cycle

| | | R1RW0408D | | | | | |
|------------------------------------|------------------|--------------|-----|--------------|-----|------|-------|
| | | 10ns Version | | 12ns Version | | | |
| Parameter | Symbol | Min | Max | Min | Max | Unit | Notes |
| Write cycle time | t _{WC} | 10 | — | 12 | — | ns | |
| Address valid to end of write | t _{AW} | 7 | — | 8 | — | ns | |
| Chip select to end of write | t _{CW} | 7 | — | 8 | — | ns | 9 |
| Write pulse width | t _{WP} | 7 | — | 8 | — | ns | 8 |
| Address setup time | t _{AS} | 0 | — | 0 | — | ns | 6 |
| Write recovery time | t _{WR} | 0 | — | 0 | — | ns | 7 |
| Data to write time overlap | t _{DW} | 5 | — | 6 | — | ns | |
| Data hold from write time | t _{DH} | 0 | — | 0 | — | ns | |
| Write disable to output in low-Z | t _{OW} | 3 | — | 3 | — | ns | 1 |
| Output disable to output in high-Z | t _{OHZ} | — | 5 | — | 6 | ns | 1 |
| Write enable to output in high-Z | t _{WHZ} | — | 5 | — | 6 | ns | 1 |

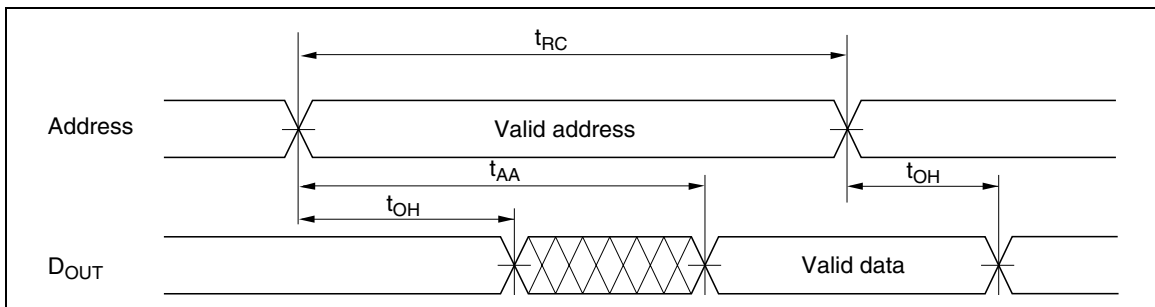
- Notes: 1. Transition is measured ± 200 mV from steady voltage with output load (B). This parameter is sampled and not 100% tested.
2. Address should be valid prior to or coincident with CS# transition low.
3. WE# and/or CS# must be high during address transition time.
4. If CS# and OE# are low during this period, I/O pins are in the output state. Then, the data input signals of opposite phase to the outputs must not be applied to them.
5. If the CS# low transition occurs simultaneously with the WE# low transition or after the WE# transition, output remains a high impedance state.
6. t_{AS} is measured from the latest address transition to the later of CS# or WE# going low.
7. t_{WR} is measured from the earlier of CS# or WE# going high to the first address transition.
8. A write occurs during the overlap of a low CS# and a low WE#. A write begins at the latest transition among CS# going low and WE# going low. A write ends at the earliest transition among CS# going high and WE# going high. t_{WP} is measured from the beginning of write to the end of write.
9. t_{CW} is measured from the later of CS# going low to the end of write.

Timing Waveforms

Read Timing Waveform (1) ($WE\# = V_{IH}$)

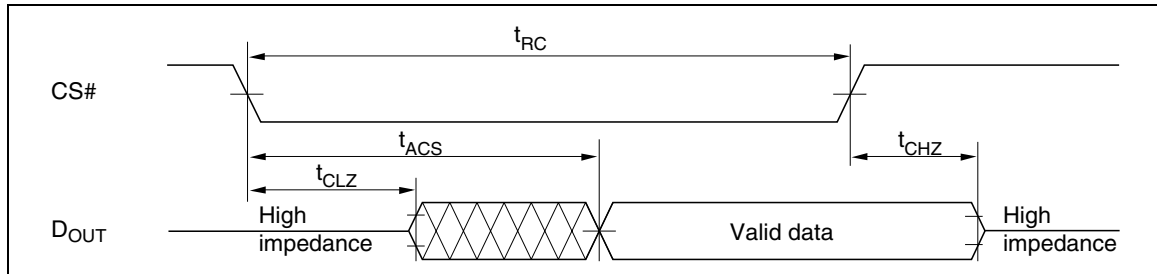


Read Timing Waveform (2) ($WE\# = V_{IH}$, $CS\# = V_{IL}$, $OE\# = V_{IL}$)

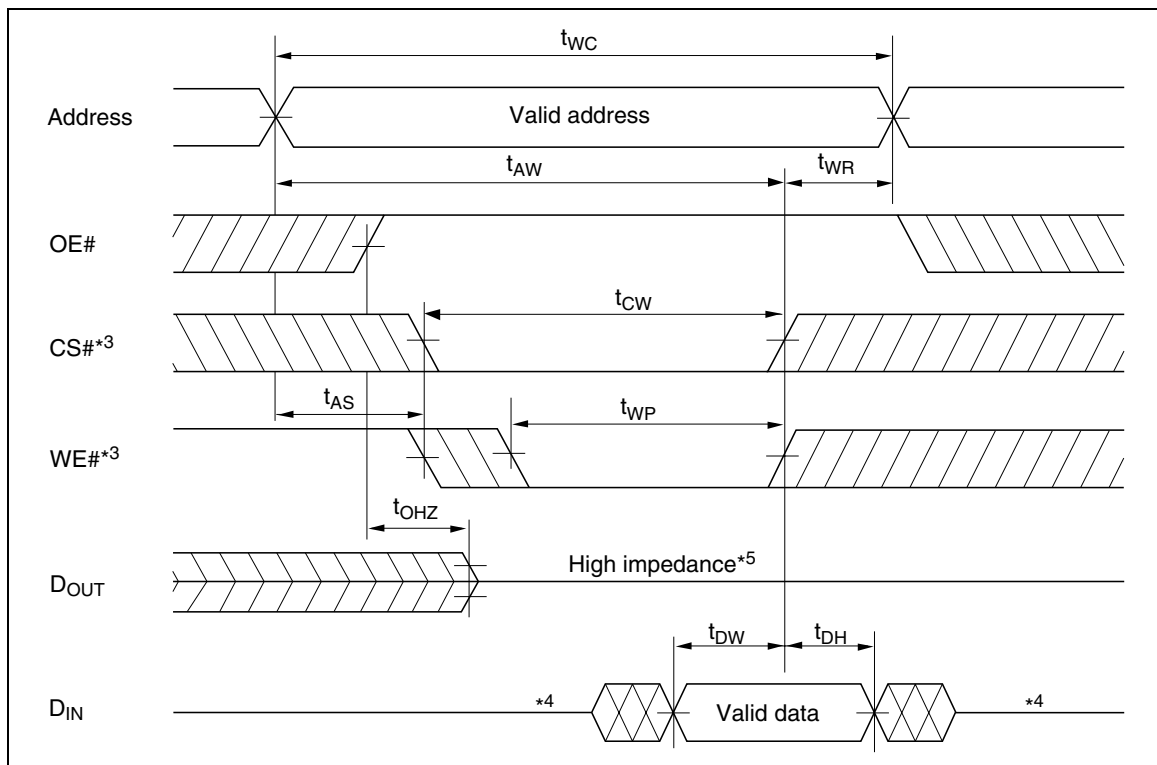


R1RW0408D Series

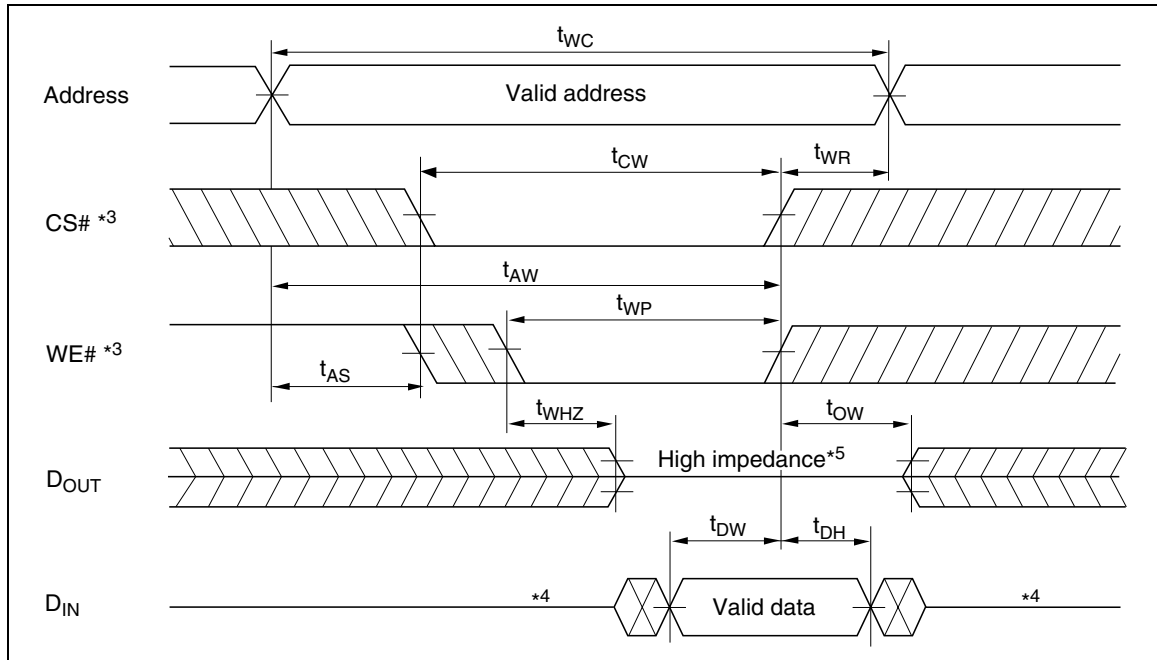
Read Timing Waveform (3) ($WE\# = V_{IH}$, $CS\# = V_{IL}$, $OE\# = V_{IL}$)*²



Write Timing Waveform (1) ($WE\#$ Controlled)



Write Timing Waveform (2) (CS# Controlled)



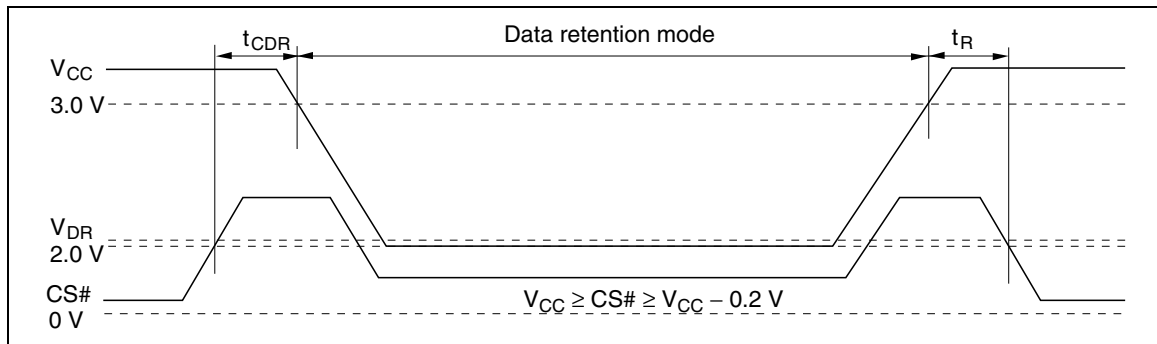
Low V_{CC} Data Retention Characteristics

($T_a = 0$ to $+70^\circ\text{C}$)

This characteristics is guaranteed only for L-version.

| Parameter | Symbol | Min | Max | Unit | Test conditions |
|--------------------------------------|------------|-----|-----|---------------|---|
| V_{CC} for data retention | V_{DR} | 2.0 | — | V | $V_{CC} \geq CS\# \geq V_{CC} - 0.2\text{ V}$ (1) $0\text{ V} \leq V_{IN} \leq 0.2\text{ V}$ or (2) $V_{CC} \geq V_{IN} \geq V_{CC} - 0.2\text{ V}$ |
| Data retention current | I_{CCDR} | — | 400 | μA | $V_{CC} = 3\text{ V}$, $V_{CC} \geq CS\# \geq V_{CC} - 0.2\text{ V}$ (1) $0\text{ V} \leq V_{IN} \leq 0.2\text{ V}$ or (2) $V_{CC} \geq V_{IN} \geq V_{CC} - 0.2\text{ V}$ |
| Chip deselect to data retention time | t_{CDR} | 0 | — | ns | See retention waveform |
| Operation recovery time | t_R | 5 | — | ms | |

Low V_{CC} Data Retention Timing Waveform



Revision History

R1RW0408D Series Data Sheet

| Rev. | Date | Contents of Modification | |
|------|---------------|--------------------------|---|
| | | Page | Description |
| 0.01 | Sep. 30, 2003 | — | Initial issue |
| 1.00 | Mar.12.2004 | — | Deletion of Preliminary |
| 2.00 | Dec.01.2008 | — | Part Number 10ns Version Adding |
| | | P1 | Features Access time 10ns and operating current 115mA adding |
| | | P2 | Order Information Type No R1RW0408DGE-0PRAdding |
| | | | DC Characteristics Operating power supply current 10ns parameter adding |
| | | P7 | AC Characteristics Read ,Write parameter 10ns parameter adding |
| | | P8/P9 | |

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